

# Sound Processor with Built-in 3-band Equalizer

#### **BD37542FS**

#### **General Description**

BD37542FS is a sound processor with built-in 3-band equalizer for car audio. The functions are stereo input selector (which can switch single and ground isolation input), input-gain control, main volume, loudness, 5ch fader volume, LPF for subwoofer and mixing input. Moreover, "Advanced switch circuit", which is an original ROHM technology, can reduce various switching noise (ex. No-signal, low frequency like 20Hz & large signal inputs). Also, "Advanced switch" makes control of microcomputer easier, and can construct a high quality car audio system.

#### **Features**

- Reduced switching noise of input gain control, mute, main volume, fader volume, bass, middle, treble, loudness, mixing by using advanced switch circuit.
- Built-in differential input selector that can make various combination of single-ended / differential input.
- Built-in ground isolation amplifier inputs, which is ideal for external stereo input.
- Built-in input gain controller reduces switching noise for volume of a portable audio input.
- Decreased the number of external components due to built-in 3-band equalizer filter, LPF for subwoofer. It is possible to control Q, Gv, fo of 3-band equalizer, fc of LPF, and Gv of loudness by I<sup>2</sup>C BUS control.
- It is possible to adjust the gain of the bass, middle, treble up to ±20dB with 1 dB step gain adjustment.
- It is equipped with output terminals for Subwoofer. Moreover, the stereo signal output of the front and rear can also be chosen by the I<sup>2</sup>C BUS control.
- Built-in mixing input and mixing attenuator.
- Energy-saving design resulting in low-current consumption is achieved by utilizing the Bi-CMOS process. It has the advantage in quality over scaling down the power heat control of the internal regulators.
- Input terminals and output terminals are organized and separately laid out to keep the signal flow in one direction which results in simpler and smaller PCB layout.
- It is possible to control the I<sup>2</sup>C BUS by 3.3V / 5V.

#### **Applications**

It is optimal for car audio systems. It can also be used for audio equipment of mini Compo, micro Compo, TV, etc.

#### **Key Specifications**

Power Supply Voltage Range: 7.0V to 9.5VCircuit Current (No Signal): 38mA(Typ)

■ Total Harmonic Distortion 1:

(FRONT,REAR) 0.001%(Typ)

Total Harmonic Distortion 2:

(SUBWOOFER) 0.002%(Typ)

■ Maximum Input Voltage: 2.3Vrms (Typ)

■ Cross-talk Between Selectors: -100dB (Typ)

Volume Control Range: +15 dB to -79dB

Output Noise Voltage 1:

(FRONT,REAR) 3.8µVrms(Typ)

Output Noise Voltage 2:

(SUBWOOFER) 4.8μVrms(Typ)
Residual Output Noise Voltage: 1.8μVrms(Typ)

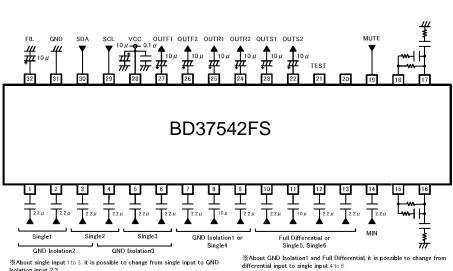
Residual Output Noise voltage: 1.8µvrms(1yp)
 Operating Temperature Range: -40°C to +85°C

#### **Package**

W(Typ) x D(Typ) x H(Max)

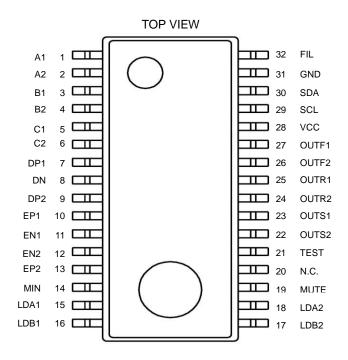


## **Typical Application Circuit**



Unit R : [Ω] C : [F]

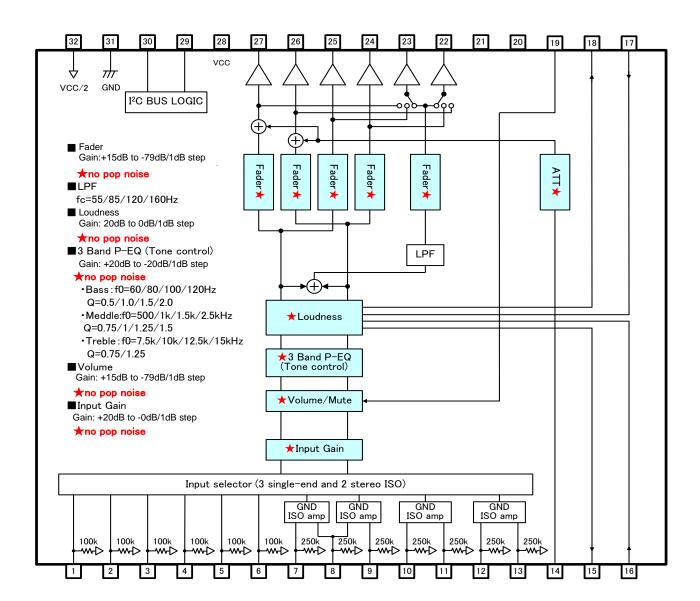
## **Pin Configuration**



**Pin Descriptions** 

Fill Descri	ptions				
Pin No.	Pin Name	Description	Pin No.	Pin Name	Description
1	A1	A input terminal of 1ch	17	LDB2	Loudness setting terminal of 2ch
2	A2	A input terminal of 2ch	18	LDA2	Loudness setting terminal of 2ch
3	B1	B input terminal of 1ch	19	MUTE	External compulsory mute terminal
4	B2	B input terminal of 2ch	20	N.C.	No Connection
5	C1	C input terminal of 1ch	21	TEST	Test Pin
6	C2	C input terminal of 2ch	22	OUTS2	Subwoofer output terminal of 2ch
7	DP1	D positive input terminal of 1ch	23	OUTS1	Subwoofer output terminal of 1ch
8	DN	D negative input terminal	24	OUTR2	Rear output terminal of 2ch
9	DP2	D positive input terminal of 2ch	25	OUTR1	Rear output terminal of 1ch
10	EP1	E positive input terminal of 1ch	26	OUTF2	Front output terminal of 2ch
11	EN1	E negative input terminal of 1ch	27	OUTF1	Front output terminal of 1ch
12	EN2	E negative input terminal of 2ch	28	VCC	Power supply terminal
13	EP2	E positive input terminal of 2ch	29	SCL	I <sup>2</sup> C Communication clock terminal
14	MIN	Mixing input terminal	30	SDA	I <sup>2</sup> C Communication data terminal
15	LDA1	Loudness setting terminal of 1ch	31	GND	GND terminal
16	LDB1	Loudness setting terminal of 1ch	32	FIL	VCC/2 terminal

## **Block Diagram**



## **Absolute Maximum Ratings** (Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Supply Voltage	Vcc	10.0	V
Input Voltage	VIN	Vcc+0.3 to GND-0.3	V
Power Dissipation	Pd	0.95 (Note 1)	W
Storage Temperature	Tstg	-55 to +150	°C

(Note 1) When mounted on the standard board (70 x 70 x 1.6 mm³), derate by 7.6mW/°C for Ta above 25°C.

Thermal resistance  $\theta$ ja = 131.6(°C/W)

Material: A FR4 grass epoxy board(3% or less of copper foil area)

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

#### **Recommended Operating Conditions**

Parameter	Symbol	Min	Тур	Max	Unit
Power Supply Voltage	Vcc	7.0	-	9.5	V
Temperature	Topr	-40	-	+85	°C

#### **Electrical Characteristics**

(Unless specified otherwise, Ta=25°C,  $V_{CC}$ =8.5V, f=1kHz,  $V_{IN}$ =1Vrms, Rg=600 $\Omega$ , RL=10k $\Omega$ , A1 input, Input gain 0dB, Mute OFF, Volume 0dB, Tone control 0dB, Loudness 0dB, LPF OFF, Mixing OFF, Fader 0dB)

<u> </u>	Parameter		011,	Limit	1,1440		O a madistia ma
BLOCK	Parameter	Symbol	Min	Тур	Max	Unit	Conditions
	Circuit Current (No Signal)	IQ	-	38	48	mA	No signal
	Voltage Gain	G∨	-1.5	0	+1.5	dB	G <sub>V</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> )
	Channel Balance	СВ	-1.5	0	+1.5	dB	$CB = G_{V1}\text{-}G_{V2}$
	Total Harmonic Distortion 1 (FRONT,REAR)	THD+N1	-	0.001	0.05	%	V <sub>OUT</sub> =1Vrms BW=400Hz-30KHz
	Total Harmonic Distortion 2 (SUBWOOFER)	THD+N2	-	0.002	0.05	%	V <sub>OUT</sub> =1Vrms BW=400Hz-30KHz
GENERAL	Output Noise Voltage 1 (FRONT,REAR) *	V <sub>NO1</sub>	-	3.8	15	μVrms	$Rg = 0\Omega$ BW = IHF-A
GENI	Output Noise Voltage 2 (SUBWOOFER) *	V <sub>NO2</sub>	-	4.8	15	μVrms	$Rg = 0\Omega$ BW = IHF-A
	Residual Output Noise Voltage *	Vnor	-	1.8	10	μVrms	Fader = $-\infty$ dB Rg = $0\Omega$ BW = IHF-A
	Crosstalk Between Channels *	СТС	-	-100	-90	dB	Rg = $0\Omega$ CTC= $20log(V_{OUT}/V_{IN})$ BW = IHF-A
	Ripple Rejection	RR	-	-70	-40	dB	f=1kHz V <sub>RR</sub> =100mVrms RR=20log(V <sub>CC</sub> IN/V <sub>OUT</sub> )
	Input Impedance(A, B,C)	R <sub>IN_S</sub>	70	100	130	kΩ	
~	Input Impedance(D, E)	R <sub>IN_D</sub>	175	250	325	kΩ	
SELECTOR	Maximum Input Voltage	V <sub>IM</sub>	2.1	2.3	-	Vrms	V <sub>IM</sub> at THD+N(V <sub>OUT</sub> )=1% BW=400Hz-30KHz
UT SELE	Crosstalk Between Selectors *	CTS	-	-100	-90	dB	Rg = $0\Omega$ CTS= $20log(V_{OUT}/V_{IN})$ BW = IHF-A
INPUT	Common Mode Rejection Ratio *	CMRR	50	65	-	dB	XP1 and XN input XP2 and XN input CMRR=20log(V <sub>IN</sub> /V <sub>OUT</sub> ) BW = IHF-A,[*XD,E]

## **Electrical Characteristics - continued**

CUIC	al Characteristics - continued						
BLOCK	Parameter	Symbol		Limit	ı	Unit	Conditions
BL	r dramotor	Cymbol	Min	Тур	Max	O.III	Conditions
GAIN	Minimum Input Gain	GIN_MIN	-2	0	+2	dB	Input gain 0dB V <sub>IN</sub> =100mVrms G <sub>IN</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> )
NPUT GAIN	Maximum Input Gain	G <sub>IN_MAX</sub>	18	20	22	dB	Input gain 20dB VIN=100mVrms GIN=20log(VOUT/VIN)
	Gain Set Error	G <sub>IN_ERR</sub>	-2	0	+2	dB	GAIN=+1dB to +20dB
MUTE	Mute Attenuation *	G <sub>мите</sub>	-	-105	-85	dB	Mute ON $G_{MUTE}=20log(V_{OUT}/V_{IN})$ $BW = IHF-A$
	Maximum Gain	Gv max	13	15	17	dB	Volume = 15dB $V_{IN}$ =100mVrms $G_V$ =20log( $V_{OUT}/V_{IN}$ )
VOLUME	Maximum Attenuation *	Gv_min	-	-100	-85	dB	Volume = -∞dB Gv=20log(V <sub>OUT</sub> /V <sub>IN</sub> ) BW = IHF-A
10/	Attenuation Set Error 1	Gv_err1	-2	0	+2	dB	GAIN & ATT=+15dB to -15dB
	Attenuation Set Error 2	G <sub>V_ERR2</sub>	-3	0	+3	dB	ATT=-16dB to -47dB
	Attenuation Set Error 3	G <sub>V_ERR3</sub>	-4	0	+4	dB	ATT=-48DB to -79DB
S	Maximum Boost Gain	G <sub>B_BST</sub>	18	20	22	dB	Gain=+20dB f=100Hz V <sub>IN</sub> =100mVrms G <sub>B</sub> =20log (V <sub>OUT</sub> /V <sub>IN</sub> )
BASS	Maximum Cut Gain	G <sub>В_СUТ</sub>	-22	-20	-18	dB	Gain=-20dB f=100Hz V <sub>IN</sub> =2Vrms G <sub>B</sub> =20log (V <sub>OUT</sub> /V <sub>IN</sub> )
	Gain Set Error	G <sub>B_ERR</sub>	-2	0	+2	dB	Gain=-20dB to +20dB f=100Hz
щ	Maximum Boost Gain	G <sub>м_вѕт</sub>	18	20	22	dB	Gain=+20dB f=1kHz V <sub>IN</sub> =100mVrms G <sub>M</sub> =20log (V <sub>OUT</sub> /V <sub>IN</sub> )
MIDDLE	Maximum Cut Gain	<b>G</b> м_сит	-22	-20	-18	dB	Gain=-20dB f=1kHz V <sub>IN</sub> =2Vrms G <sub>M</sub> =20log (V <sub>OUT</sub> /V <sub>IN</sub> )
	Gain Set Error	G <sub>M_ERR</sub>	-2	0	+2	dB	Gain=-20dB to +20dB f=1kHz
	Maximum Boost Gain	G <sub>T_BST</sub>	18	20	22	dB	Gain=+20dB f=10kHz V <sub>IN</sub> =100mVrms GT=20log (VouT/V <sub>IN</sub> )
TREBLE	Maximum Cut Gain	<b>G</b> т_сит	-22	-20	-18	dB	Gain=-20dB f=10kHz V <sub>IN</sub> =2Vrms G <sub>T</sub> =20log (V <sub>OUT</sub> /V <sub>IN</sub> )
	Gain Set Error	G <sub>T_ERR</sub>	-2	0	+2	dB	Gain=-20dB to +20dB f=10kHz
	Input Impedance	R <sub>IN_M</sub>	19	27	35	kΩ	
9 U	Maximum Input Voltage	V <sub>ІМ_М</sub>	2.0	2.2	-	Vrms	V <sub>IM</sub> at THD+N(V <sub>OUT</sub> )=1% BW=400Hz-30KHz
MIXING	Maximum Attenuation	G <sub>MX_MIN</sub>	-	-100	-85	dB	MIX=OFF G <sub>MX</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> ) BW=INF-A
	Maximum Gain	Gмх_мах	5	7	9	dB	ATT=+6dB G <sub>MX</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> )

## **Electrical Characteristics - continued**

3LOCK	Parameter	Cumbal		Limit		Unit	Conditions
BLC	Parameter	Symbol	Min	Тур	Max	Unit	Conditions
	Maximum Boost Gain	G <sub>F_BST</sub>	13	15	17	dB	Fader=15dB V <sub>IN</sub> =100mVrms G <sub>F</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> )
SUBWOOFER	Maximum Attenuation *	G <sub>F_MIN</sub>	-	-100	-90	dB	Fader = -∞dB G <sub>F</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> ) BW = IHF-A
BWC	Gain Set Error	G <sub>F_ERR</sub>	-2	0	+2	dB	Gain=+1dB to +15dB
US/	Attenuation Set Error 1	G <sub>F_ERR1</sub>	-2	0	+2	dB	ATT=-1dB to -15dB
-ADER	Attenuation Set Error 2	G <sub>F_ERR2</sub>	-3	0	+3	dB	ATT=-16dB to -47dB
FAC	Attenuation Set Error 3	G <sub>F_ERR3</sub>	-4	0	+4	dB	ATT=-48dB to -79dB
	Output Impedance	Rouт	-	-	50	Ω	V <sub>IN</sub> =100mVrms
	Maximum Output Voltage	V <sub>OM</sub>	2	2.2	-	Vrms	THD+N=1 % BW=400Hz-30KHz
LOUDNESS	Maximum Gain	G <sub>L_MAX</sub>	17	20	23	dB	Gain 20dB V <sub>IN</sub> =100mVrms G <sub>L</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> )
ron	Gain Set Error	G <sub>L_ERR</sub>	-2	0	+2	dB	Gain=+1dB to +20dB

VP-9690A(Average value detection, effective value display) filter by Matsushita Communication is used for \* measurement. Phase between input / output is same.

## **Typical Performance Curves**

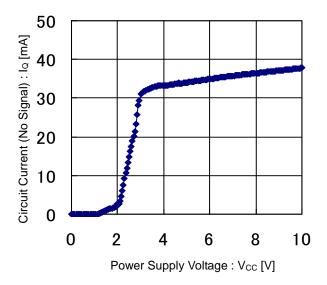


Figure 1. Circuit Current (No Signal) vs Power Supply Voltage

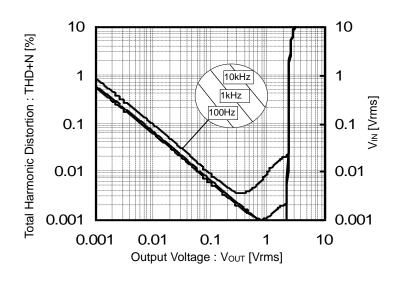


Figure 2. Total Harmonic Distortion vs Output Voltage

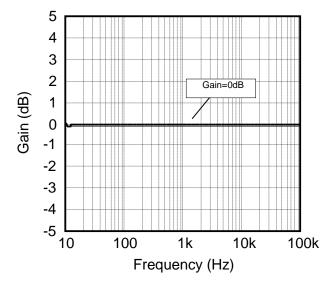


Figure 3. Gain vs Frequency

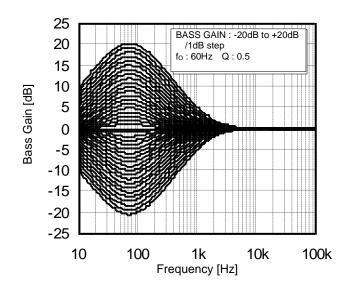


Figure 4. Bass Gain vs Frequency

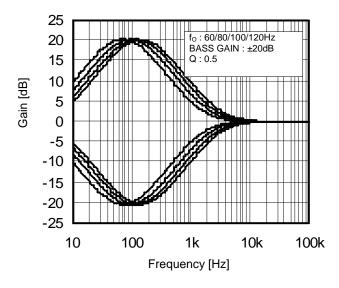


Figure 5. Bass fo vs Frequency

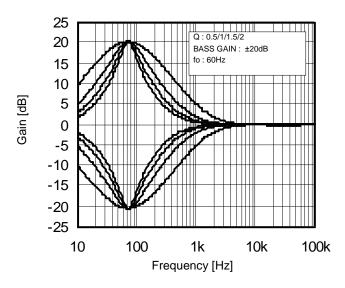


Figure 6. Bass Q vs Frequency

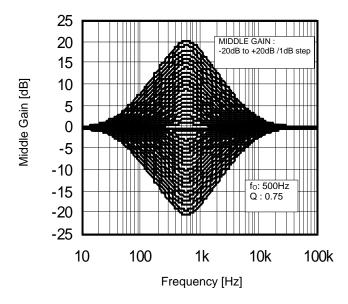


Figure 7. Middle Gain vs Frequency

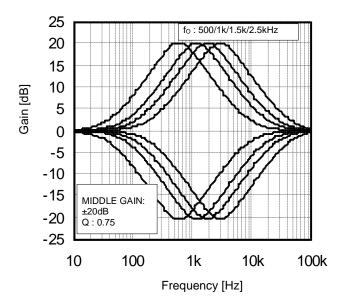


Figure 8. Middle fo vs Frequency

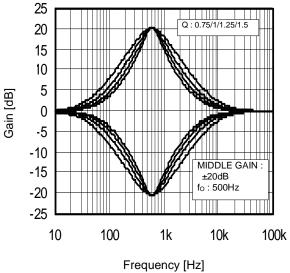


Figure 9. Middle Q vs Frequency

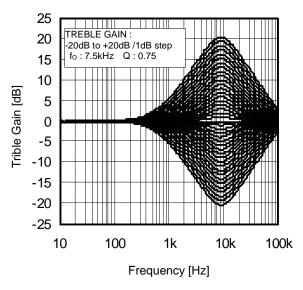


Figure 10. Treble Gain vs Frequency

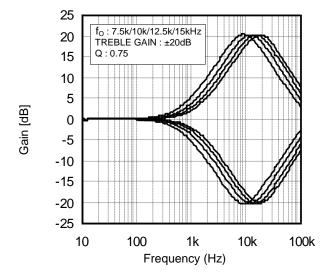


Figure 11. Treble fo vs Frequency

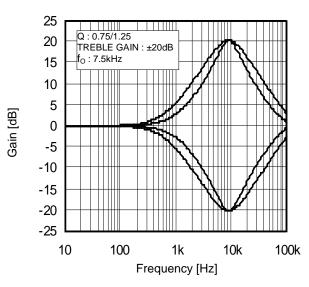


Figure 12. Treble Q vs Frequency

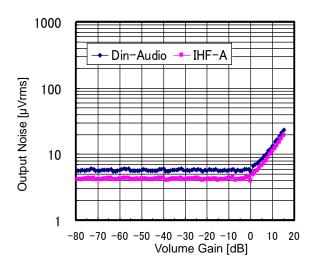


Figure 13. Output Noise vs Volume Gain

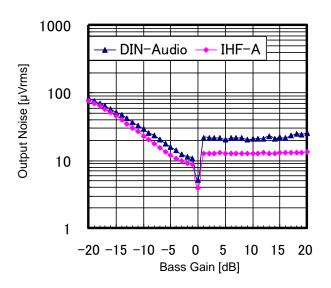


Figure 14. Output Noise vs Bass Gain

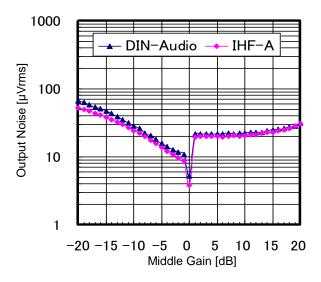


Figure 15. Output Noise vs Middle Gain

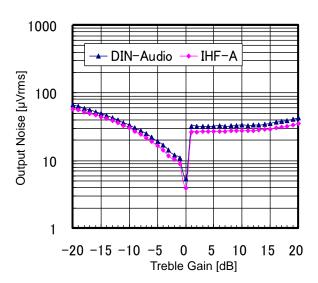


Figure 16. Output Noise vs Treble Gain

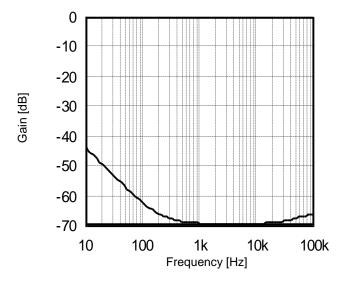


Figure 17. CMRR vs Frequency

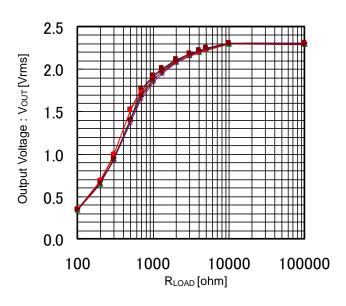


Figure 18. Output Voltage vs RLOAD

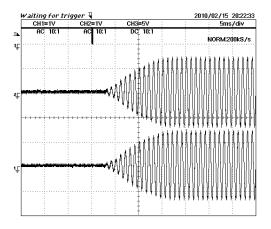


Figure 19. Advanced Switch 1

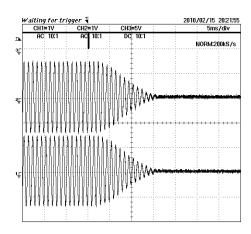


Figure 20. Advanced Switch 2

## **Timing Chart**

#### **CONTROL SIGNAL SPECIFICATION**

## (1) Electrical Specifications and Timing for Bus Lines and I/O Stages

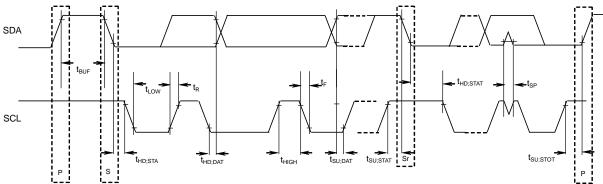


Figure 21. I<sup>2</sup>C-bus Signal Timing Diagram

Table 1 Characteristics of the SDA and SCL bus lines for I2C-bus devices (Ta=25°C, V<sub>CC</sub>=8.5V)

	Parameter	Symbol	Fast-mode	e I <sup>2</sup> C-bus	Unit
	i didilietei	Symbol	Min	Max	Offic
1	SCL clock frequency	fscL	0	400	kHz
2	Bus free time between a STOP and START condition	t <sub>BUF</sub>	1.3	-	μS
3	Hold time (repeated) START condition. After this period, the first clock	tup ora	0.6		μS
3	pulse is generated	thd;sta	0.6	-	μΟ
4	LOW period of the SCL clock	tLOW	1.3	-	μS
5	HIGH period of the SCL clock	thigh	0.6	ı	μS
6	Set-up time for a repeated START condition	t <sub>SU;STA</sub>	0.6	1	μS
7	Data hold time:	thd;dat	0.06 (Note)	ı	μS
8	Data set-up time	tsu;dat	120	1	ns
9	Set-up time for STOP condition	t <sub>SU;STO</sub>	0.6	1	μS

All values refer to VIH Min and VIL Max Levels (see Table 2).

(Note) A device must internally provide a hold time of at least 300 ns for the SDA signal (referred to the VIH Min of the SCL signal) in order to bridge the undefined region of the falling edge of SCL.

For 7(thd:Dat), 8(tsu:Dat), make the setup in which the margin is full.

Table 2 Characteristics of the SDA and SCL I/O stages for I<sup>2</sup>C-bus devices

	Parameter	Cumbal	Fast-mode	Unit	
	Parameter	Symbol	Min	Max	Unit
10	LOW level input voltage:	$V_{IL}$	-0.3	+1	V
11	HIGH level input voltage:	ViH	2.3	5	V
12	Pulse width of spikes which must be suppressed by the input filter.	tsp	0	50	ns
13	LOW level output voltage: at 3mA sink current	$V_{OL1}$	0	0.4	V
14	Input current each I/O pin with an input voltage between 0.4V and 4.5V.	lı	-10	+10	μΑ

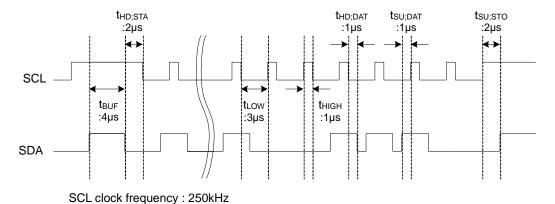


Figure 22. A Command Timing Example in the I<sup>2</sup>C Data Transmission

#### (2) I<sup>2</sup>C BUS FORMAT

	MSB LSB		MSB	LSB		MSB L	SB					
S	Slave Address	A Select Address		dress	Α	Data		Α	Р			
1bit	8bit	1bit	8b	it	1bit	8bit		1bit	1bit			
	S	= Start condition (Recognition of start bit)										
	Slave Address	= Re	= Recognition of slave address. The first 7 bits correspond to the slave address.									
		Th	e least signific	ant bit is '	"L" wł	nich corresponds to	write	mode	Э.			
	Α	= AC	KNOWLEDG	E bit (Rec	ognit	ion of acknowledger	nent)					
	Select Address	= Select address corresponding to volume, bass or treble.										
	Data	= Data on every volume and tone.										
	Р	= Sto	op condition (F	Recognitio	n of s	stop bit)						

#### (3) I<sup>2</sup>C BUS Interface Protocol

(a) Basic Format

S	Slave Addı	ress	Α	Select Addre	SS	Α	Data	l	Α	Р
	MSB LSB			MSB	LSB	Λ	/ISB	LS	BB	

(b) Automatic Increment (Select Address increases (+1) according to the number of data.)

S	S Slave Address		Α	Select Ad	dress	Α	Data	a1	Α	Data2	Α		DataN	Α	Р
	MSB LS			MSB	LSB		MSB	LSE	3	MSB	LSB	}	MSB	LS	SB

(Example) ①Data1 shall be set as data of address specified by Select Address.

- ②Data2 shall be set as data of address specified by Select Address +1.
- ③DataN shall be set as data of address specified by Select Address +N-1.

(c) Configuration Unavailable for Transmission (In this case, only Select Address1 is set.)

S	Sla	ve Addre	ss /	Α	Select A	ddress1	Α	Da	ata	Α	Select	Addres	ss 2	Α	Da	ta	Α	Р
	MSB	3 L	SB	MS	SB	LSB	M	ISB	LSE	3	MSB		LSB	Ν	1SB	LS	В	
( Note )If any data is transmitted as Select Address 2 next to data, it is recognized																		
	as data, not as Select Address 2.																	

#### (4) Slave Address

MSB							LSB	
A6	A5	A4	A3	A2	A1	A0	R/W	
1	0	0	0	0	0	0	0	80H

## (5) Select Address & Data

Items	Select Address	MSB Data							LSB
items	(hex)	D7	D6	D5	D4	D3	D2	D1	D0
Initial setup 1	01	Advanced switch ON/OFF	0	of Input G Tone/Fade	switch time ain/Volume er/Loudness xing	0	1		ed switch of Mute
Initial setup 2	02	LPF Phase	0		fer Output elect	0	Sul	owoofer LP	F fc
Initial setup 3	03	0	0	0	0	0	0	1	0
Input Selector	05	Full-diff Type	0	0		Ir	put selector	•	
Input gain	06	Mute ON/OFF	0	0 Input Gain					
Volume gain	20			\	/olume Gain	/ Attenuation	1		
Fader 1ch Front	28				Fader Gain /	Attenuation			
Fader 2ch Front	29				Fader Gain /	Attenuation			
Fader 1ch Rear	2A	Fader Gain / Attenuation							
Fader 2ch Rear	2B				Fader Gain /	Attenuation			
Fader Subwoofer	2C				Fader Gain /	Attenuation			
Mixing	30				Mixing Gain.	/ Attenuation			
Bass setup	41	0	0	Bas	ss f <sub>O</sub>	0	0	Ba	ss Q
Middle setup	44	0	0	Midd	dle fo	0	0	Mid	dle Q
Treble setup	47	0	0	Trek	ole f <sub>O</sub>	0	0	0	Treble Q
Bass gain	51	Bass Boost/ Cut	0	0			Bass Gain		
Middle gain	54	Middle Boost/ Cut	0	0	Middle Gain				
Treble gain	57	Treble Boost/ Cut	0	0	Treble Gain				
Loudness Gain	75	0	Loudness Gain						
System Reset	FE	1	0	0	0	0	0	0	1

: Advanced switch

#### Note

- 1. The Advance Switch works in the latch part while changing from one function to another.
- 2. Upon continuous data transfer, the Select Address rolls over because of the automatic increment function, as shown below.

$$01 \rightarrow 02 \rightarrow 03 \rightarrow 05 \rightarrow 06 \rightarrow 20 \rightarrow 28 \rightarrow 29 \rightarrow 2A \rightarrow 2B \rightarrow 2C$$

$$30 \rightarrow 41 \rightarrow 44 \rightarrow 47 \rightarrow 51 \rightarrow 54 \rightarrow 57 \rightarrow 75$$

- 3. Advanced switch is not used for the function of input selector, subwoofer output select, etc. Therefore, please apply mute on the side when changing these settings.
- 4. When using mute function of this IC at the time of changing input selector, please switch mute ON/OFF while waiting for advanced-mute time.

Select address 01 (hex)

Time	MSB	Ad	Advanced switch time of Mute							
Time	D7	D6	D5	D4	D3	D2	D1	D0		
0.6msec	A di (2 12 2 2 2 d		Advanced	Advanced switch time			0	0		
1.0msec	Advanced Switch	0	of Input gain/Volume Tone/Fader/Loudness		0	1	0	1		
1.4msec	ON/OFF						1	0		
3.2msec	ON/OFF	Mix		king			1	1		

Time	мѕв	Advanced switch time of Input MSB gain/Volume/Tone/Fader/ LSB Loudness/Mixing									
	D7	D6	D5	D4	D3	D2	D1	D0			
4.7 msec	۸ مار رو رو م		0	0							
7.1 msec	Advanced	_	0	1	0	1	Advanced switch Time of Mute				
11.2 msec	Switch ON/OFF	-	1	0							
14.4 msec		ON/OFF		1	1	1					

Mode	MSB	ISB Advanced switch ON/OFF LSB									
Mode	D7	D6	D5	D4	D3	D2	D1	D0			
OFF	0	0	of Input ga	switch time ain/Volume	0	1	Advanced switch				
ON	1	J	Tone/Fader/Loudness Mixing		,	'	Time of Mute				

Select address 02(hex)

Coloot dadi ood oz(110x)										
fo	MSB Subwoofer LPF fc L									
tc	D7	D6	D5	D4	D3	D2	D1	D0		
OFF						0	0	0		
55Hz						0	0	1		
85Hz	LPF	0	Subwoof	er Output	0	0	1	0		
120Hz	Phase	0	Se	Select		0	1	1		
160Hz						1	0	0		
Prohibition							]			

Mode	MSB	MSB Subwoofer Output Select LS									
Mode	D7	D6	D5	D4	D3	D2	D1	D0			
LPF	LPF Phase		0	0							
Front		•	0	1		Subwoofer LPF fc					
Rear		Phase	1	0	Ü						
Prohibition			1	1							

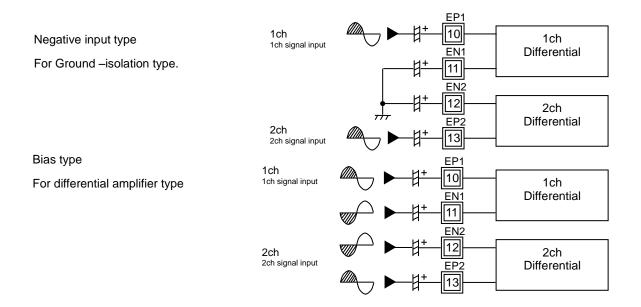
Phase	MSB				LSB			
Filase	D7	D6	D5	D4	D3	D2	D1	D0
0°	0	0	Subwoofer output select		0	Cubwo of or LDE to		
180°	1	U			U	Subwoofer LPF		-r ic

Select address 05(hex)

Mode		-	MSB			Input	Selector			LSB
iviode	OUTF1	OUTF2	D7	D6	D5	D4	D3	D2	D1	D0
Α	A1	A2				0	0	0	0	0
В	B1	B2			0	0	0	0	1	
С	C1	C2				0	0	0	1	0
D single	DP1	DP2				0	0	0	1	1
E1 single	EP1	EN1	Full-	Full- diff bias type 0		0	1	0	1	0
E2 single	EN2	EP2	diff bias		0	0	1	0	1	1
A diff	A1	B1				0	1	1	1	1
C diff	B2	C2	select			1	0	0	0	0
D diff	DP1	DP2				0	0	1	1	0
E full diff	EP1	EP2			•	0	1	0	0	0
Inp	Input SHORT					0	1	0	0	1
Prohibition						0	ther setting			

Input SHORT : The input impedance of each input terminal is lowered from 100kΩ(Typ) to 6 kΩ(Typ). (For quick charge of coupling capacitor)

Mode	MSB Full-diff Bias Type Select								
Wode	D7	D6	D5	D4	D3	D2	D1	D0	
Negative Input	0	0	0		Inn	ut Calaatar	,		
Bias	1	U		Input Selector					



Select address 06 (hex)

Mode	MSB			Input	Gain			LSB	
Mode	D7	D6	D5	D4	D3	D2	D1	D0	
0dB				0	0	0	0	0	
1dB				0	0	0	0	1	
2dB				0	0	0	1	0	
3dB				0	0	0	1	1	
4dB				0	0	1	0	0	
5dB				0	0	1	0	1	
6dB				0	0	1	1	0	
7dB				0	0	1	1	1	
8dB				0	1	0	0	0	
9dB				-	0	1	0	0	1
10dB				0	1	0	1	0	
11dB	Mute	_	0	0	1	0	1	1	
12dB	ON/OFF	0		0	1	1	0	0	
13dB				0	1	1	0	1	
14dB				0	1	1	1	0	
15dB				0	1	1	1	1	
16dB				1	0	0	0	0	
17dB				1	0	0	0	1	
18dB				1	0	0	1	0	
19dB				1	0	0	1	1	
20dB				1	0	1	0	0	
				1	1	0	1	1	
Prohibition				:	:	:	:	:	
				1	1	1	1	1	

Mode	MSB Mute ON/OFF								
Mode	D7	D6	D5	D4	D3	D2	D1	D0	
OFF	0	0	0			Innut Cain			
ON	1	U	U	Input Gain					

Select address 20, 28, 29, 2A, 2B, 2C (hex)

Gain & ATT	MSB	Vo	I, Fad	er Gai	n / Att	enuati	ion	LSB
Gain & ATT	D7	D6	D5	D4	D3	D2	D1	D0
	0	0	0	0	0	0	0	0
	0	0	0	0	0	0	0	1
Prohibition	:	:	:	:	:	:	:	:
	0	1	1	1	0	0	0	0
15dB	0	1	1	1	0	0	0	1
14dB	0	1	1	1	0	0	1	0
13dB	0	1	1	1	0	0	1	1
:	:	:	:	:	:	:	:	:
-77dB	1	1	0	0	1	1	0	1
-78dB	1	1	0	0	1	1	1	0
-79dB	1	1	0	0	1	1	1	1
	1	1	0	1	0	0	0	0
Prohibition	:	:	:	:	:	:	:	:
	1	1	1	1	1	1	1	0
-∞dB	1	1	1	1	1	1	1	1

Select address 30(hex)

Gain & ATT	MSB		Mixing	Gain	/ Atte	nuatio	n	LSB
Gaill & Al I	D7	D6	D5	D4	D3	D2	D1	D0
	0	0	0	0	0	0	0	0
	0	0	0	0	0	0	0	1
Prohibition	:	••	•••	••	:	••	÷	:
	0	1	1	1	1	0	0	0
7dB	0	1	1	1	1	0	0	1
6dB	0	1	1	1	1	0	1	0
5dB	0	1	1	1	1	0	1	1
:	:	:	:	:	:	:	:	:
-77dB	1	1	0	0	1	1	0	1
-78dB	1	1	0	0	1	1	1	0
-79dB	1	1	0	0	1	1	1	1
	1	1	0	1	0	0	0	0
Prohibition	:	:	:	• •	÷	• •	•	:
	1	1	1	1	1	1	1	0
MIX OFF	1	1	1	1	1	1	1	1

Select address 41(hex)

Q factor	MSB		В	ass	Q fact	or		LSB
Qiacioi	D7	D6	D5	D4	D3	D2	D1	D0
0.5							0	0
1.0	_	0	Pos	o f	0	0	0	1
1.5	0		Bass f <sub>0</sub>		U	U	1	0
2.0							1	1

fo	MSB			Bass	LSB			
10	D7	D6	D5	D4	D3	D2	D1	D0
60Hz			0	0				
80Hz	_	0	0	1			Ва	ass actor
100Hz	0	U	1	0	1 0	U	Q fa	actor
120Hz	]		1	1	]			

Select address 44(hex)

_	oloot addition 1 I(IIOX)									
	Q factor	MSB		Middle Q factor						
	QTactor	D7	D6	D5	D4	D3	D2	D1	D0	
	0.75							0	0	
	1.0	_	0	Middle f	vio f-		0	0	1	
	1.25			iviido	Middle f <sub>O</sub>		0	1	0	
	1.5							1	1	

fo	MSB			Middl	LSB			
10	D7	D6	D5	D4	D3	D2	D1	D0
500Hz			0	0				
1kHz	0	0	0	1	0	0	Mic	ddle
1.5kHz	U	U	1	0	U	U	Q fa	actor
2.5kHz			1	1				

Select address 47 (hex)

O factor	Q factor MSB D7		Treble			Q factor		
QTactor			D5	D4	D3 D2 D1		D1	D0
0.75	0	0	Trob	ulo f	0	0	0	0
1.25	] 0	0	nec	ole fo	U	0	0	1

fo	MSB			Treble fo					
To	D7	D6	D5	D4	D3	D2	D1	D0	
7.5kHz		0	0	0		0	0		
10kHz	_		0	1	_			Treble Q factor	
12.5kHz	] 0		1	0	U			Q factor	
15kHz			1	1					

Gain	MSB		E	Bass/Middle	/Treble Gai	n		LSB							
Gairi	D7	D6	D5	D4	D3	D2	D1	D0							
0dB				0	0	0	0	0							
1dB				0	0	0	0	1							
2dB				0	0	0	1	0							
3dB				0	0	0	1	1							
4dB				0	0	1	0	0							
5dB				0	0	1	0	1							
6dB				0	0	1	1	0							
7dB				0	0	1	1	1							
8dB				0	1	0	0	0							
9dB											0	1	0	0	1
10dB	Bass/			0	1	0	1	0							
11dB	Middle/			0	1	0	1	1							
12dB	Treble	0	0	0	1	1	0	0							
13dB	Boost			0	1	1	0	1							
14dB	/cut			0	1	1	1	0							
15dB				0	1	1	1	1							
16dB				1	0	0	0	0							
17dB				1	0	0	0	1							
18dB				1	0	0	1	0							
19dB				1	0	0	1	1							
20dB				1	0	1	0	0							
•				1	0	1	0	1							
Prohibition				:	:	:	:	:							
i ioillollioii				1	1	1	1	0							
			ĺ	1	1	1	1	1							

Mode	MSB Bass/Middle/Treble Boost/Cut								
Mode	D7 D6 D5 D4 D3 D2 D1 D0								
Boost	0	0	0		Page/I	Middle/Trobl	o Coin		
Cut	1	] 0	0	Bass/Middle/Treble Gain					

Select address 75 (hex)

OC	ieci addiess 75 (liex)	,							
	Mode	MSB Lo			oudness Hicut				LSB
	D		D6	D5	D4	D3	D2	D1	D0
	Hicut1		0	0					
	Hicut2	_	0	1					
	Hicut3	U	1	0			oudness Ga	urı	
	Hicut4		1	1					

Gain	MSB		Lo	oudne	ss Ga	in		LSB	
Gain	D7	D6	D5	D4	D3	D2	D1	D0	
0dB				0	0	0	0	0	
1dB	]			0	0	0	0	1	
2dB				0	0	0	1	0	
3dB				0	0	0	1	1	
4dB				0	0	1	0	0	
5dB	]			0	0	1	0	1	
6dB	]			0	0	1	1	0	
7dB				0	0	1	1	1	
8dB				0	1	0	0	0	
9dB				0	1	0	0	1	
10dB				0	1	0	1	0	
11dB	0	Loudne	se Hicut	0	1	0	1	1	
12dB		Loudiless in	iess i lieut	Loudness Hicut	0	1	1	0	0
13dB				0	1	1	0	1	
14dB				0	1	1	1	0	
15dB				0	1	1	1	1	
16dB				1	0	0	0	0	
17dB				1	0	0	0	1	
18dB				1	0	0	1	0	
19dB				1	0	0	1	1	
20dB	]			1	0	1	0	0	
				1	0	1	0	1	
Prohibition			:	:	:	:	:		
				1	1	1	1	1	

: Initial condition

## (6) About Power ON Reset

Built-in IC initialization is made during power ON of the supply voltage. Please send initial data to all addresses at supply voltage on. And please turn on mute until this initial data is sent.

Parameter	Symbol	Limit			Unit	Conditions	
Farameter	Symbol	Min	Тур	Max	Offic	Conditions	
Rise Time of VCC	trise	33	-	-	µsec	V <sub>CC</sub> rise time from 0V to 5V	
VCC Voltage of Release Power ON Reset	VPOR	1	4.1	-	V		

#### (7) About External Compulsory Mute Terminal

It is possible to force mute externally by setting an input voltage to the MUTE terminal.

Mute Voltage Condition	Mode		
GND to 1.0V	MUTE ON		
2.3V to V <sub>CC</sub>	MUTE OFF		

Establish the voltage of MUTE in the condition you want to set.

## **Application Information**

1. Function and Specifications

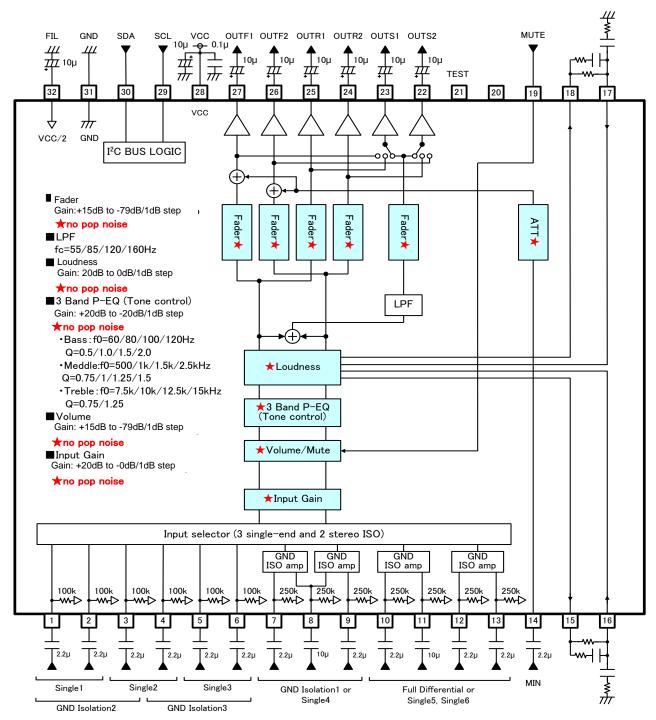
Function	tions Specifications										
	· Stereo input										
	· Single-End/Diff/Full-Diff										
	(Possible to set the number of single-end/diff/full-diff as follows)										
	Single-End Differential Full-Differential										
Input	Mode 1	0	3	1							
selector	Mode 2	1	2	1							
	Mode 3 Mode 4	<u>3</u> 4	0	1							
	Mode 5	5	1	0							
	Mode 6	6	0	0							
	<u> </u>	Table.1 Combi	nation of input se	elector							
Innut gain	· +20dB to 0d	dB (1dB step)									
Input gain	· Possible to	use "Advanced s	witch" for preven	tion of switching noise.							
Mute	· Possible to	use "Advanced s	witch" for preven	tion of switching noise.							
Values s	· +15dB to -7	9dB (1dB step),	-∞dB								
Volume	Possible to use "Advanced switch" for prevention of switching noise.										
	· +20dB to -20dB (1dB step)										
Bass	· Q=0.5, 1, 1.5, 2										
Dass	· fo=60, 80, 100, 120Hz										
	· Possible to use "Advanced switch" for prevention of switching noise.										
	· +20dB to -20dB (1dB step)										
Middle	· Q=0.75, 1, 1.25, 1.5										
Middle	· fo =500, 1k, 1.5k 2.5kHz										
	Possible to use "Advanced switch" for prevention of switching noise.										
	· +20dB to -20dB (1dB step)										
Treble	· Q=0.75, 1.25										
TIEDIC	· f <sub>0</sub> =7.5k, 10k, 12.5k, 15kHz										
	Possible to use "Advanced switch" for prevention of switching noise.										
Fader	· +15dB to -79dB(1dB step), -∞dB										
1 4401	· Possible to use "Advanced switch" for prevention of switching noise.										
Loudness	· 20dB to 0dB(1dB step)										
	Possible to use "Advanced switch" for prevention of switching noise.										
LPF	· f <sub>C</sub> =55/85/120Hz/160Hz, pass										
_, ,	· Phase shift	(0°/180°)									
	· Monaural in	put									
Mixing	· +7dB to -79	dB (1dB step), -	∘dB								
	Possible to use "Advanced switch" for prevention of switching noise.										

## 2. Volume / Fader Volume / Mixing Attenuation Data

(dB)	D7	D6	D5	D4	D3	D2	D1	D0	(dB)	D7	D6	D5	D4	D3	D2	D1	D0
+15	0	1	1	1	0	0	0	1	-33	1	0	1	0	0	0	0	1
+14	0	1	1	1	0	0	1	0	-34	1	0	1	0	0	0	1	0
+13	0	1	1	1	0	0	1	1	-35	1	0	1	0	0	0	1	1
+12	0	1	1	1	0	1	0	0	-36	1	0	1	0	0	1	0	0
+11	0	1	1	1	0	1	0	1	-37	1	0	1	0	0	1	0	1
+10	0	1	1	1	0	1	1	0	-38	1	0	1	0	0	1	1	0
+9	0	1	1	1	0	1	1	1	-39	1	0	1	0	0	1	1	1
+8	0	1	1	1	1	0	0	0	-40	1	0	1	0	1	0	0	0
+7	0	1	1	1	1	0	0	1	-41	1	0	1	0	1	0	0	1
+6	0	1	1	1	1	0	1	0	-42	1	0	1	0	1	0	1	0
+5	0	1	1	1	1	0	1	1	-43	1	0	1	0	1	0	1	1
+4	0	1	1	1	1	1	0	0	-44	1	0	1	0	1	1	0	0
+3	0	1	1	1	1	1	0	1	-45	1	0	1	0	1	1	0	1
+2	0	1	1	1	1	1	1	0	-46	1	0	1	0	1	1	1	0
+1	0	1	1	1	1	1	1	1	-47	1	0	1	0	1	1	1	1
0	1	0	0	0	0	0	0	0	-48	1	0	1	1	0	0	0	0
-1	1	0	0	0	0	0	0	1	-49	1	0	1	1	0	0	0	1
-2	1	0	0	0	0	0	1	0	-50	1	0	1	1	0	0	1	0
-3	1	0	0	0	0	0	1	1	-51	1	0	1	1	0	0	1	1
-4	1	0	0	0	0	1	0	0	-52	1	0	1	1	0	1	0	0
-5	1	0	0	0	0	1	0	1	-53	1	0	1	1	0	1	0	1
-6	1	0	0	0	0	1	1	0	-54	1	0	1	1	0	1	1	0
-7	1	0	0	0	0	1	1	1	-55	1	0	1	1	0	1	1	1
-8	1	0	0	0	1	0	0	0	-56	1	0	1	1	1	0	0	0
-9	1	0	0	0	1	0	0	1	-57	1	0	1	1	1	0	0	1
-10	1	0	0	0	1	0	1	0	-58	1	0	1	1	1	0	1	0
-11	1	0	0	0	1	0	1	1	-59	1	0	1	1	1	0	1	1
-12	1	0	0	0	1	1	0	0	-60	1	0	1	1	1	1	0	0
-13	1	0	0	0	1	1	0	1	-61	1	0	1	1	1	1	0	1
-14	1	0	0	0	1	1	1	0	-62	1	0	1	1	1	1	1	0
-15	1	0	0	0	1	1	1	1	-63	1	0	1	1	1	1	1	1
-16	1	0	0	1	0	0	0	0	-64	1	1	0	0	0	0	0	0
-17	1	0	0	1	0	0	0	1	-65	1	1	0	0	0	0	0	1
-18	1	0	0	1	0	0	1	0	-66	1	1	0	0	0	0	1	0
-19	1	0	0	1	0	0	1	1	-67	1	1	0	0	0	0	1	1
-20	1	0	0	1	0	1	0	0	-68	1	1	0	0	0	1	0	0
-21	1	0	0	1	0	1	0	1	-69	1	1	0	0	0	1	0	1
-22	1	0	0	1	0	1	1	0	-70	1	1	0	0	0	1	1	0
-23	1	0	0	1	0	1	1	1	-71	1	1	0	0	0	1	1	1
-24	1	0	0	1	1	0	0	0	-72	1	1	0	0	1	0	0	0
-25	1	0	0	1	1	0	0	1	-73	1	1	0	0	1	0	0	1
-26	1	0	0	1	1	0	1	0	-74	1	1	0	0	1	0	1	0
-27	1	0	0	1	1	0	1	1	-75 -76	1	1	0	0	1	0	1	1
-28	1	0	0	1	1	1	0	0	-76	1	1	0	0	1	1	0	0
-29	1	0	0	1	1	1	0	1	-77	1	1	0	0	1	1	0	1
-30	1	0	0	1	1	1	1	0	-78	1	1	0	0	1	1	1	0
-31	1	0	0	1	1	1	1	1	-79	1	1	0	0	1	1	1	1
-32 Mixing Adjus	1	0	1	0	0	0	0	0	-∞	1	1	1	1	1	1	1	1

Mixing Adjustable range is +7dB to -∞dB.

#### 3. Application Circuit



(Note) About single input 1 to 3, it is possible to change from single input to GND Isolation input 2,3.

(Note) About GND Isolation1 and Full Differential, it is possible to change from differential input to single input 4 to 6.

Unit R : [Ω] C : [F]

Figure 23. BD37543FS

#### Notes on wiring

- ①Please connect the decoupling capacitor of the power supply in the shortest possible distance to GND.
- 2)GND lines shall be one-point connected.
- Wiring pattern of Digital shall be away from that of analog unit and crosstalk shall not be acceptable.
- (4) If possible, SDA and SCL lines of I2C BUS shall not be parallel.
  - The lines shall be shielded, if they are adjacent to each other.
- ⑤If possible, analog input lines should not be parallel. The lines should be shielded, if they are adjacent to each other.
- 6 About TEST pin (Pin 21), please leave it OPEN.

## **Power Dissipation**

About the thermal design of the IC

Characteristics of an IC have a great deal to do with the temperature at which it is used, and exceeding absolute maximum ratings may degrade and destroy elements. Careful consideration must be given to the heat of the IC from the two standpoints of immediate damage and long-term reliability of operation.

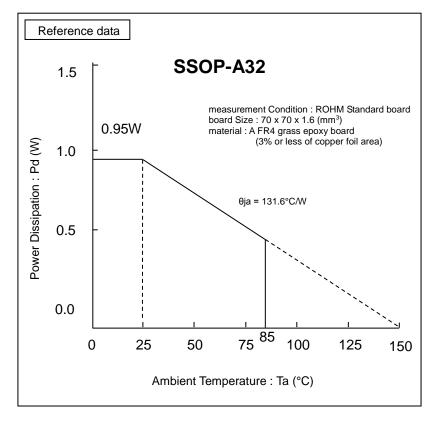


Figure 24. Temperature Derating Curve

(Note) Values are actual measurements and are not guaranteed.

Power dissipation values vary according to the board on which the IC is mounted.

## I/O Equivalent Circuits

Terminal No.	Terminal Name	Terminal Voltage	Equivalent Circuit	Terminal Description
1 2 3 4 5 6	A1 A2 B1 B2 C1 C2	4.25	VCC Δ VΘ γ \$100kΩ	A terminal for signal input. The input impedance is 100kΩ(typ).
7 8 9 10 11 12 13	DP1 DN DP2 EP1 EN1 EN2 EP2	4.25	VCC Δ Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ	Input terminal available to Single/Differential mode. The input impedance is 250kΩ(Typ).
15 18	LDA1 LDA2	4.25	VCC O J J J J J J J J J J J J J J J J J J	The loudness characteristic setting terminal.
16 17	LDB1 LDB2	4.25	VCC A BU	The loudness characteristic setting terminal.
19	MUTE	-	VCC 0.58×V <sub>CC</sub> 250kΩ 1.65V	A terminal for external compulsory mute. If terminal voltage is High level, the mute is OFF. And if the terminal voltage is Low level, the mute is on.

Values in the pin explanation and input/output equivalent circuit are reference values only and are not guaranteed.

## I/O Equivalent Circuits – continued

	Equivalent Circuits – continued								
Terminal	Terminal	Terminal	Equivalent Circuit	Terminal Description					
No.	Name	Voltage	VCC	A terminal for fader and Subwoofer output.					
22 23 24 25 26 27	OUTS2 OUTS1 OUTR2 OUTR1 OUTF2 OUTF1	4.25	GND GND	A terminal for lader and Subwooler output.					
28	VCC	8.5		Power supply terminal.					
29	SCL	-	VCC OV 1.65V	A terminal for clock input of I <sup>2</sup> C BUS communication.					
30	SDA	-	VCC O GND GND 1.65V	A terminal for data input of I <sup>2</sup> C BUS communication.					
31	GND	0		Ground terminal.					
32	FIL	4.25	VCC	1/2 VCC terminal.  Voltage for reference bias of analog signal system. The simple precharge circuit and simple discharge circuit for an external capacitor are built in.					
14	MIN	4.25	VCC A 27KΩ	A terminal for signal input. The input impedance is $27k\Omega$ (Typ).					
21	TEST	-		TEST terminal					

Values in the pin explanation and input/output equivalent circuit are reference values only and are not guaranteed

## **Operational Notes**

#### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

#### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

#### 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

#### 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

#### 11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

## **Operational Notes - continued**

#### 12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

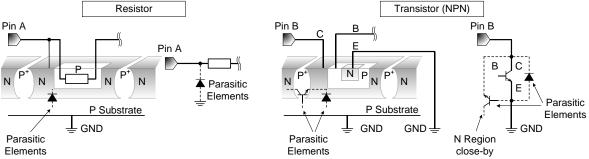
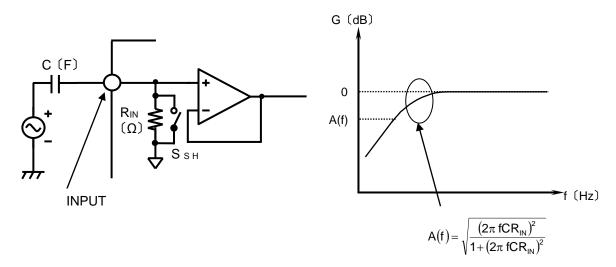


Figure 25. Example of monolithic IC structure

#### 13. About Signal Input

#### (a) About Input Coupling Capacitor Constant Value

The constant value of input coupling capacitor C(F) is decided with respect to the input impedance  $R_{IN}(\Omega)$  at the input signal terminal of the IC. The first HPF characteristic of RC is composed.



#### (b) About the Input Selector SHORT

SHORT mode is the command which makes switch  $S_{SH}$  =ON of input selector part so that the input impedance  $R_{IN}$  of all terminals becomes small. Switch  $S_{SH}$  is OFF when SHORT command is not selected. The constant time brought about by the small resistance inside and the capacitor outside the LSI becomes small when this command is used. The charge time of the capacitor becomes short. Since SHORT mode turns ON the switch of  $S_{SH}$  and makes it low impedance, please use it at no signal condition.

## **Operational Notes - continued**

#### 14. About Mute Terminal (Pin 19) when Power Supply is OFF

There should be no applied voltage across the Mute terminal (Pin 19) when power-supply is OFF. If in case voltage is supplied to mute terminal, please insert a series resistor (about  $2.2k\Omega$ ) to Mute terminal. (Please refer to Application Circuit Diagram.)

#### 15. About TEST Pin

TEST Pin should be left as OPEN. Pin 21 is TEST Pin.

#### 16. About MIX

#### (1) About Specification of Fader -∞ at MIX ON.

Mix\_signal is added to Main\_signal after Fader\_Gain(+15dB to -79dB) like the figure. When Fader is set at -∞, the signal after a MIX signal is added is done with MUTE because the -∞ circuit of Fader is in the step after the addition circuit

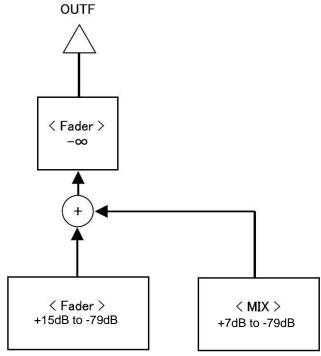
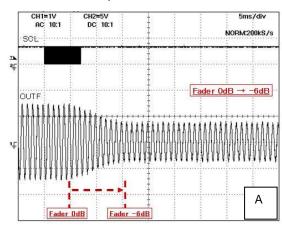


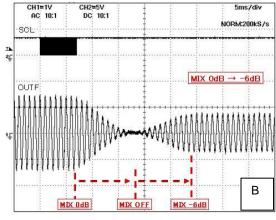
Figure 26. About Front Fader and MIX

## (2) About Advanced Switching of MIX Gain/ATT

When advanced switching of MIX\_Gain/ATT works, MIX goes a switching movement that it passes through the state of MIX\_OFF like in B figure below (from current setting MIX\_Gain/ATT to MIX\_OFF to a target setting of MIX\_Gain/ATT).



Fader\_Gain/ATT 0dB to -6dB advanced switching



MIX\_Gain/ATT 0dB to -6dB advanced switching

Figure 27. Advanced Switching Movement when MIX\_Gain/ATT is Changed

## **Operational Notes - continued**

#### 17. About the External Parts Setting of Loudness Circuit

This IC is equipped with a Loudness circuit.

The Loudness gain is fixed inside the IC but its frequency characteristic can be changed freely by adjusting the external part filter. The circuit composition of the Loudness part is shown below. Incidentally, when not using the Loudness circuit, please short the pins between LDA1(Pin 15) and LDB1(Pin 16), and between LDA2(Pin 18) and LDB2(Pin 17), so as to avoid the inner amplifier inputs to become floating.

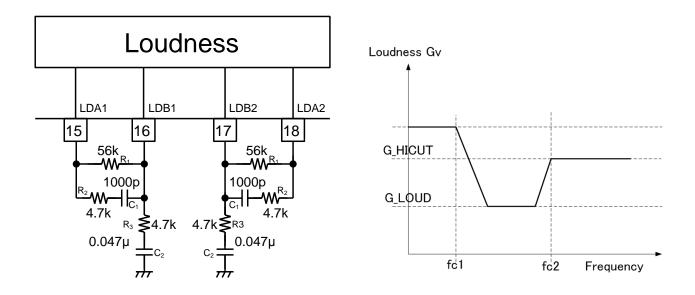


Figure 28. About the External Parts Setting of Loudness Circuit

The Loudness frequency characteristics are decided according to Figure 28. G\_LOUD can be made 20dB when external parts used are the same with Figure 28 (the recommended value). G\_LOUD is the amount of effect of Loudness when Loudness Gain is set at 20dB (P.20).

When Loudness frequency characteristics are changed, each parameter (Gain, Frequency) shown in Figure 28 can be decided using the following approximate equation below.

(Note) Design fc2 value more than one digit bigger than fc1 to get effect on Loudness.

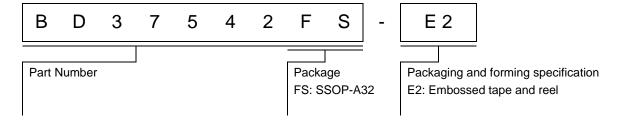
Loudness cut-off frequency

$$\begin{split} &\text{fc1} = \frac{1}{2\pi C_2 \big( R_1 + R_3 \big)} \quad \big[ \text{Hz} \big] \\ &\text{fc2} = \frac{1}{2\pi C_1 \big( R_2 + R_3 \big)} \quad \big[ \text{Hz} \big] \end{split}$$

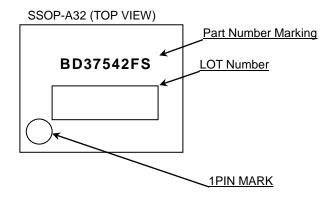
Loudness Gain (The amount of effect of Loudness)

$$\begin{split} \mathbf{G}_{\_\mathsf{LOUD}} &= 20 \log \left( \frac{R_3}{R_1 + R_3} \right) \quad \big[ \mathsf{dB} \big] \\ \mathbf{G}_{\_\mathsf{HICUT}} &= 20 \log \left( \frac{R_3}{R_1 /\!\!/ R_2 + R_3} \right) \quad \big[ \mathsf{dB} \big] \end{split}$$

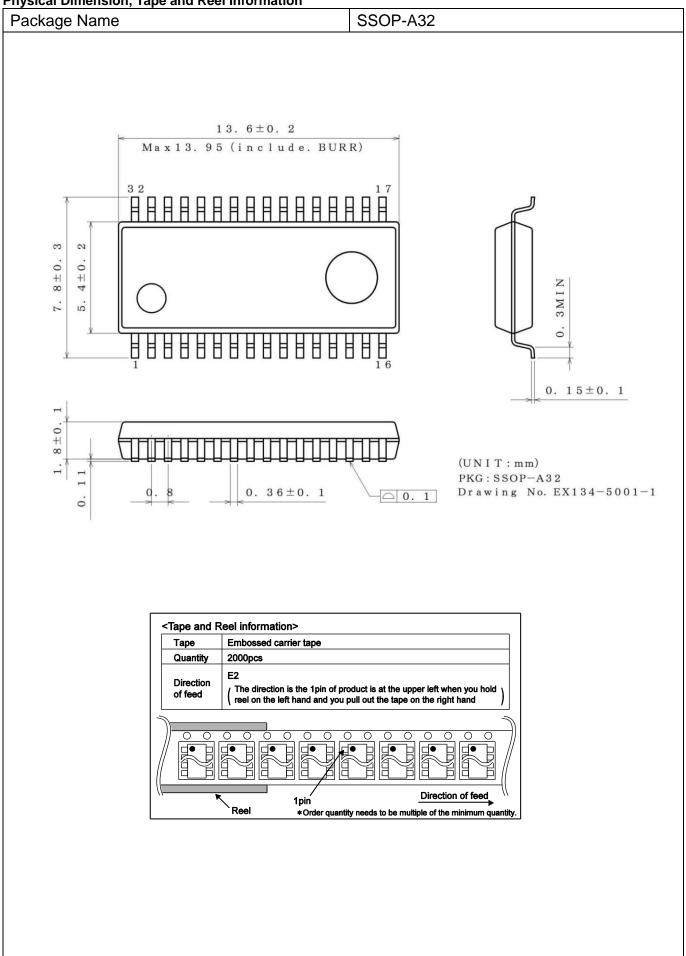
## **Ordering Information**



## **Marking Diagram**



**Physical Dimension, Tape and Reel Information** 



## **Revision History**

Date	Revision	Changes
16.Dec.2015	001	New Release

## **Notice**

#### **Precaution on using ROHM Products**

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA	
CLASSⅢ	CL ACCIII	CLASSIIb	CLASSIII	
CLASSIV	CLASSⅢ	CLASSⅢ	CLASSIII	

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

## **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

QR code printed on ROHM Products label is for ROHM's internal use only.

#### **Precaution for Disposition**

When disposing Products please dispose them properly using an authorized industry waste company.

#### **Precaution for Foreign Exchange and Foreign Trade act**

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

#### **Precaution Regarding Intellectual Property Rights**

- 1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data.
- 2. ROHM shall not have any obligations where the claims, actions or demands arising from the combination of the Products with other articles such as components, circuits, systems or external equipment (including software).
- 3. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the Products or the information contained in this document. Provided, however, that ROHM will not assert its intellectual property rights or other rights against you or your customers to the extent necessary to manufacture or sell products containing the Products, subject to the terms and conditions herein.

#### **Other Precaution**

- 1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.
- 2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.
- In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.
- 4. The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.

Notice-PGA-E Rev.002

#### **General Precaution**

- 1. Before you use our Products, you are requested to care fully read this document and fully understand its contents. ROHM shall not be in an y way responsible or liable for failure, malfunction or accident arising from the use of a ny ROHM's Products against warning, caution or note contained in this document.
- 2. All information contained in this docume nt is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sale s representative.
- 3. The information contained in this doc ument is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate an d/or error-free. ROHM shall not be in an y way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.

**Notice – WE** © 2015 ROHM Co., Ltd. All rights reserved. Rev.001

## **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ROHM Semiconductor: BD37542FS-E2



Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию.

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России, а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научноисследовательскими институтами России.

С нами вы становитесь еще успешнее!

#### Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,

Промышленная ул, дом № 19, литера Н,

помещение 100-Н Офис 331